

Notice of References Cited	Application/Control No. 09/914,687		Applicant(s)/Patent Under Reexamination BOHM ET AL.	
	Examiner John M. Villecco		Art Unit 2612	Page 1 of 1

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NON-PATENT DOCUMENTS

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	V	Kleinfelder et al.; "High Speed CMOS Image Sensor Circuits with In Situ Frame Storage"; August 2004; IEEE Transactions on Nuclear Science, Vol. 51, No. 4, pgs 1648-1656
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.